

3-of-8 Decoder/Demultiplexer 74VHC138

General Description

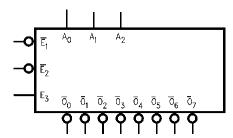
The VHC138 is an advanced high speed CMOS 3-to-8 decoder/demultiplexer fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 binary select inputs $(A_0, A_1 \text{ and } A_2)$ determine which one of the outputs $(\overline{O}_0-\overline{O}_7)$ will go LOW. When enable input E_3 is held LOW or either \overline{E}_1 or \overline{E}_2 is held HIGH, decoding function is inhibited and all outputs go HIGH. E_3 , \overline{E}_1 and \overline{E}_2 inputs are provided to ease cascade connection and for use as an address decoder for memory systems. An input protection circuit ensures that 0 V to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed: $t_{PD} = 5.7$ ns (Typ) at $T_A = 25$ °C
- Low Power Dissipation: $I_{CC} = 4 \mu A$ (Max.) at $T_A = 25 \text{ °C}$
- High Noise Immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection Provided on All Inputs
- Pin and Function Compatible with 74HC138
- These Devices are Pb-Free and are RoHS Compliant

Logic Symbols



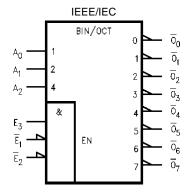
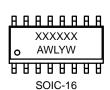


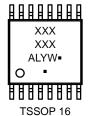
Figure 1. Logic Symbols





MARKING DIAGRAMS





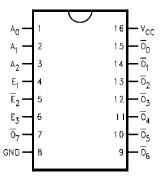
XXXXXX = Specific Device Code

A = Assembly Location

WL, L = Wafer Lot
Y = Year
WW, W = Work Week
G or = Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTIONS

Pins	Function
$\begin{array}{c} A_0 - A_2 \\ \overline{E}_1 - \overline{E}_2 \\ \overline{E}_3 \\ \overline{O}_0 - \overline{O}_7 \end{array}$	Address Inputs Enable Inputs Enable Input Outputs

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

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TRUTH TABLE

	Inputs						Out	outs					
E ₁	E ₂	E ₃	A ₀	A ₁	A ₂	O ₀	O ₁	O ₂	O ₃	O ₄	0 5	O ₆	0 ₇
H X X	X H X	X X L	X X X	X X X	X X X	H H H	H H H	HH	H H H	H H H	H H H	H H H	H H H
L L L	L L L	H H H	L H L H	L L H	L L L	L H H	H L H H	H H H	H H L	H H H	H H H	H H H	H H H
L L L	L L L	H H H	L H L H	L H H	H H H	H H H	H H H	H H H H	H H H	L H H	H L H H	H H L H	H H H L

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
V _{IN}	DC Input Voltage		-0.5 to +6.5	V
V _{OUT}	DC Output Voltage		-0.5 to V _{CC} + 0.5	V
I _{IN}	DC Input Current, per Pin		±20	mA
I _{OUT}	DC Output Current, per Pin		±25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins		±75	mA
I _{IK}	Input Clamp Current		-20	mA
I _{OK}	Output Clamp Current		±20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SOIC-16 TSSOP 16	126 159	°C/W
P _D	Power Dissipation in Still Air at 25 °C	SOIC-16 TSSOP 16	995 787	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.138 in	
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- Measured with minimum pad spacing on an FR4 board, using 76mm-by-114mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

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RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter			Max	Unit
V _{CC}	DC Supply Voltage		2.0	3.6	V
V _{IN}	DC Input Voltage (Note 4)		0	5.5	V
V _{OUT}	DC Output Voltage (Note 4)		0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
t _r , t _f	Input Rise and Fall Time $ V_{CC} = 3.0 \text{ V to } 3 $ $ V_{CC} = 4.5 \text{ V to } 5 $	3.6 V 5.5 V	0 0	100 20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

					T _A = 25 °C		;	T _A = -40 °C to 85 °C		
Symbol	Parameter	Con	ditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage			2.0 3.0–5.5	1.50 0.7 V _{CC}	-	- -	1.50 0.7 V _{CC}	_	V
V _{IL}	LOW Level Input Voltage			2.0 3.0–5.5	-	1 1	0.50 0.3 V _{CC}	-	0.50 0.3 V _{CC}	V
V _{OH}	HIGH Level Output Voltage	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	- - -	1.9 2.9 4.4	1 1 1	V
			$I_{OH} = -4 \text{ mA}$ $I_{OH} = -8 \text{ mA}$	3.0 4.5	2.58 3.94	-	_ _	2.48 3.80	_	V
V _{OL}	LOW Level Output Voltage	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1	- - -	0.1 0.1 0.1	V
			$I_{OL} = 4 \text{ mA}$ $I_{OL} = 8 \text{ mA}$	3.0 4.5	_	-	0.36 0.36	_ _	0.44 0.44	V
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND		0–5.5	-	ı	±0.1	-	±1.0	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC} c$	or GND	5.5	_	_	4.0	-	40.0	μΑ

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AC ELECTRICAL CHARACTERISTICS

					T _A = 25 °C			T _A = -40 °C to 85 °C	
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay	C _L = 15 pF	3.3 ±0.3	-	8.2	11.4	1.0	13.5	ns
t _{PHL}	A_n to \overline{O}_n	C _L = 50 pF		-	10.0	15.8	1.0	18.0	1
	C _L = 15 pF	5.0 ±0.5	-	5.7	8.1	1.0	9.5	ns	
	C _L = 50 pF		-	7.2	10.1	1.0	11.5	1	
$\begin{array}{c} t_{PLH}, \\ t_{PHL} \end{array}$ Propagation Dela E_3 to \overline{O}_n	Propagation Delay	C _L = 15 pF	3.3 ±0.3	-	8.1	12.8	1.0	15.0	ns
	E ₃ to O _n	C _L = 50 pF		-	10.6	16.3	1.0	18.5	1
		C _L = 15 pF	5.0 ±0.5	-	5.6	8.1	1.0	9.5	ns
		C _L = 50 pF		-	7.1	10.1	1.0	11.5	1
t _{PLH} ,	Propagation Delay	C _L = 15 pF	3.3 ±0.3	-	8.2	11.4	1.0	13.5	ns
t _{PHL}	\overline{E}_1 or \overline{E}_2 to \overline{O}_n	C _L = 50 pF		-	10.7	14.9	1.0	17.0	1
		C _L = 15 pF	5.0 ±0.5	-	5.8	8.1	1.0	9.5	ns
		C _L = 50 pF		-	7.3	10.1	1.0	11.5	1
C _{IN}	Input Capacitance	V _{CC} = Open	-	-	4	10	-	10	pF
C _{PD}	Power Dissipation Capacitance	(Note 5)	-	-	34	_	_	-	pF

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} x V_{CC} x f_{IN} + I_{CC}.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74VHC138MX	VHC138G	SOIC-16 (Pb-Free)	2500 Tape & Reel
74VHC138MTCX	VHC 138	TSSOP 16 (Pb-Free)	2500 Tape & Reel

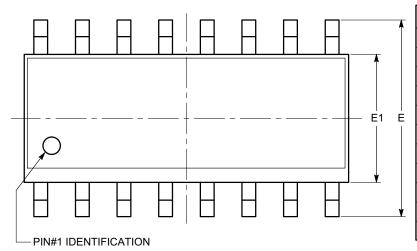
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





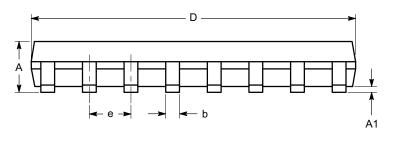
SOIC-16, 150 mils CASE 751BG ISSUE O

DATE 19 DEC 2008

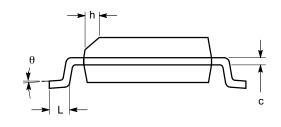


SYMBOL	MIN	NOM	MAX
Α	1.35		1.75
A1	0.10		0.25
b	0.33		0.51
С	0.19		0.25
D	9.80	9.90	10.00
Е	5.80	6.00	6.20
E1	3.80	3.90	4.00
е		1.27 BSC	
h	0.25		0.50
L	0.40		1.27
θ	0°		8°

TOP VIEW



SIDE VIEW



END VIEW

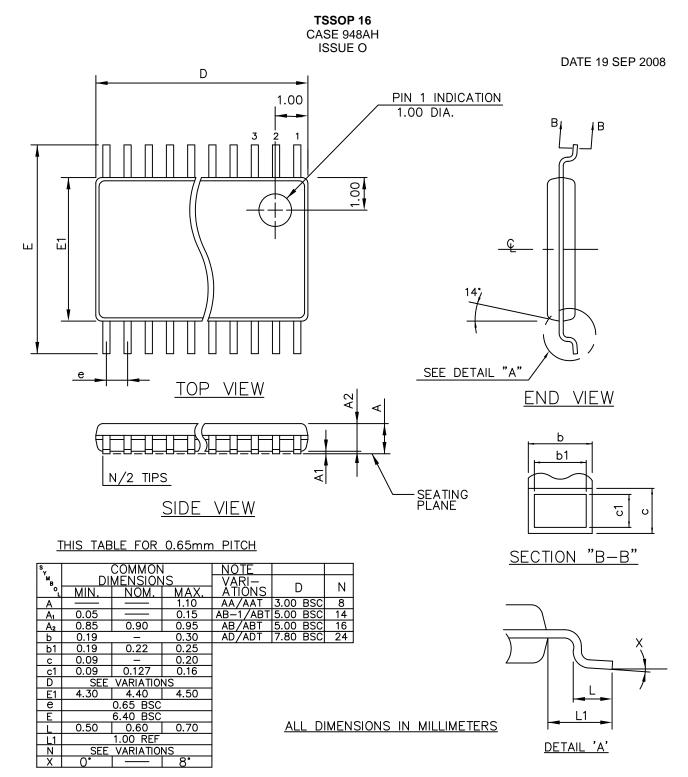
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-012.

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